Semiconductor Device Set - Page 1 of 1

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## Inclosure Material:

Ceramic all transistor and metal all transistor

## Overall Length:

0.960 inches all transistor and 0.990 inches all transistor

## Overall Height:

0.235 inches all transistor and 0.300 inches all transistor

## Overall Width:

### 0.750 inches all transistor

## End Application:

Radio set an/arc-143

## Mounting Facility Quantity:

2 all transistor

## Internal Configuration:

Junction contact all transistor
Internal Junction Configuration:
Npn all transistor
Component Function Relationship:
Matched
Component Name And Quantity:
5 transistor

## Mounting Method:

Unthreaded hole all transistor

## Semiconductor Material:

Silicon all transistor

## Voltage Rating In Volts Per Characteristic:

60.0 collector to emitter voltage, dc with base short-circuited to emitter all transistor and 50.0 collector to emitter reverse voltage all transistor and 33.0 collector to emitter voltage/static/base open all transistor and 4.0 emitter to base voltage, static, collector open all transistor

## Current Rating Per Characteristic:

8.00 amperes source cutoff current all transistor

## Power Rating Per Characteristic:

140.0 watts small-signal input power, common-collector absolute all transistor

## Maximum Operating Tempurature Per Measurement Point:

200.0 degrees celsius junction all transistor

## Terminal Type And Quantity:

3 ribbon all transistor
Shelf Life:
N/a
Unit Of Measure:

Demilitarization:
No
Fiig:
A110a0

